

STTH20004TV1

Datasheet - production data

Ultrafast high voltage rectifier

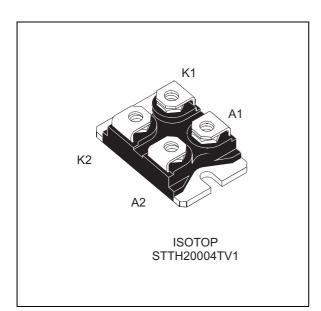


Table 1. Device summary

Symbol	Value
I _{F(AV)}	Up to 2 x 120 A
V _{RRM}	400 V
T _j (max)	150 °C
V _F (typ)	0.83 V
t _{rr} (max)	60 ns

Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- Insulated package:
 - Electrical insulation = 2500 V rms
 - Capacitance = 189 pF
- ECOPACK[®]2 compliant component

Description

The STTH20004TV1 uses ST new 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification diode.

This is information on a product in full production.

1 Characteristics

Symbol	Param		Value	Unit		
V _{RRM}	Repetitive peak reverse voltage		400	V		
I _{F(RMS)}	Forward rms current			200	А	
	Average forward current $\delta = 0.5$	T _c = 75 °C	Per diode	100	A	
'F(AV)	$I_{F(AV)}$ Average forward current, $\delta = 0.5$	T _c = 55 °C	Per diode	120		
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$			900	А	
T _{stg}	Storage temperature range	-55 to + 150	°C			
Тj	Maximum operating junction temperature			150	°C	

Table 2. Absolute ratings (limiting values, per diode)

Table 3. Thermal parameter

Symbol	Parameter	Maximum	Unit	
В		Per diode	0.60	
R _{th(j-c)}	Junction to case	Total		°C/W
R _{th(c)}	Coupling		0.10	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th}(j-c) \text{ (per diode)}} + P_{\text{(diode2)}} \times R_{\text{th}(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V - V			100	
Reverse leakage c	Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		100	1000	μA
V _F ⁽²⁾ Forward voltage drop	Forward voltage drop	T _j = 25 °C	L = 100 A			1.2	V
	Forward voltage drop	T _j = 150 °C	I _F = 100 A		0.83	1.0	v

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the maximum conduction losses use the following equation: P = 0.8 x $I_{F(AV)}$ + 0.002 ${I_F}^2_{(RMS)}$



Symbol	Parameter	Parameter		Min.	Тур.	Max.	Unit	
t _{rr}	Reverse recovery time	T _j = 25 °C	I _F = 1 A, dI _F /dt = 50 A/μs, V _R = 30 V		75	100		
			I _F = 1 A, dI _F /dt = 200 A/µs, V _R = 30 V		45	60	ns	
t _{fr}	Forward recovery time		I _F = 100 A,			800	ns	
V _{FP}	Forward recovery voltage	T _j = 25 °C	$j = 25 \text{ °C}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$		2.6		V	
I _{RM}	Reverse recovery current	T 405.00	= 125 °C $I_F = 100 \text{ A},$ $dI_F/dt = 100 \text{ A}/\mu s,$ $V_R = 200 \text{ V}$			18	А	
S _{factor}		$T_j = 125 ^{\circ}C$			0.4		-	

Table 5. Dynamic characteristics

Figure 1. Conduction losses versus average forward current (per diode)

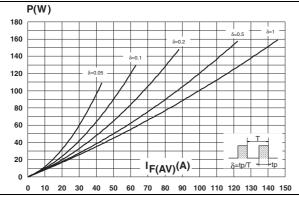
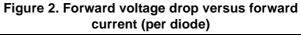


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration



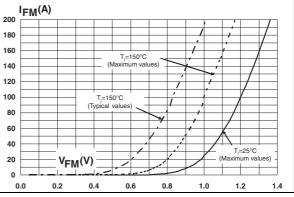


Figure 4. Peak reverse recovery current versus dl_F/dt (typical values, per diode)

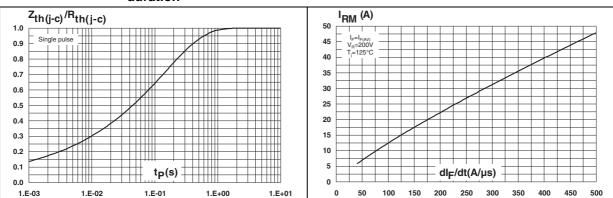




Figure 5. Reverse recovery time versus dl_F/dt (typical values, per diode)

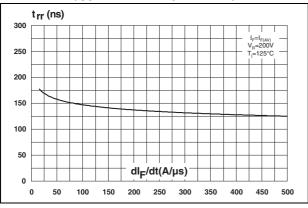


Figure 7. Reverse recovery time versus dl_F/dt (typical values, per diode)

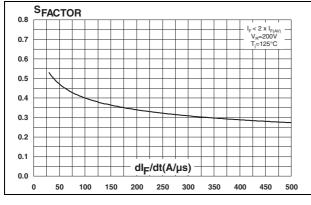


Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl_F/dt dl_F/dt (typical values, per diode)

Q_{rr} (nC)

Figure 6. Reverse recovery charges versus

dl_F/dt (typical values, per diode)

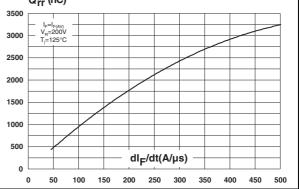
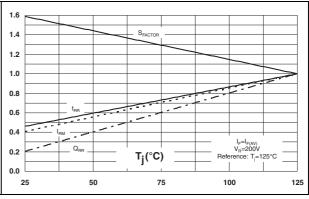
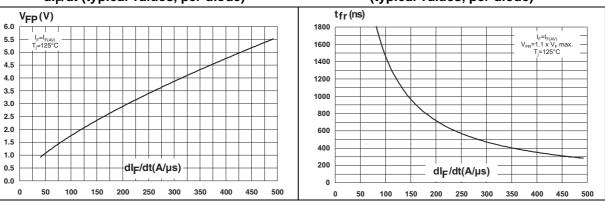


Figure 8. Relative variations of dynamic parameters versus junction temperature



(typical values, per diode)





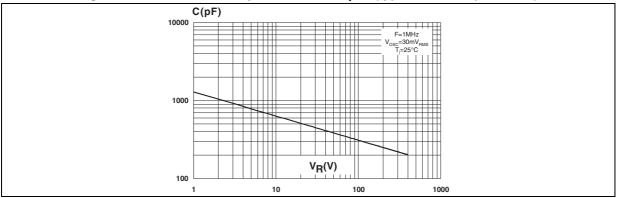


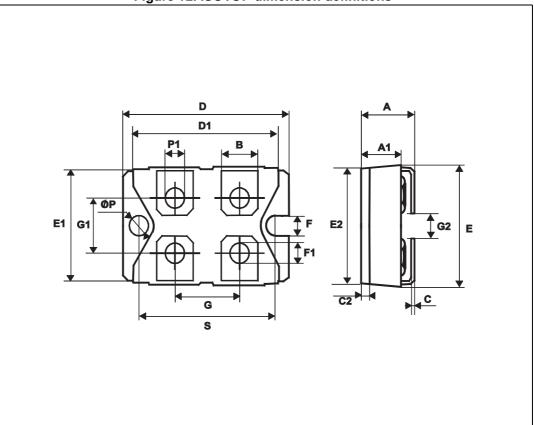
Figure 11. Reverse recovery time versus dl_F/dt (typical values, per diode)

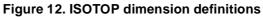


2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.







		Dimensions						
Ref.		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	11.80		12.20	0.465		0.480		
A1	8.90		9.10	0.350		0.358		
В	7.8		8.20	0.307		0.323		
С	0.75		0.85	0.030		0.033		
C2	1.95		2.05	0.077		0.081		
D	37.80		38.20	1.488		1.504		
D1	31.50		31.70	1.240		1.248		
E	25.15		25.50	0.990		1.004		
E1	23.85		24.15	0.939		0.951		
E2		24.80			0.976			
G	14.90		15.10	0.587		0.594		
G1	12.60		12.80	0.496		0.504		
G2	3.50		4.30	0.138		0.169		
F	4.10		4.30	0.161		0.169		
F1	4.60		5.00	0.181		0.197		
Р	4.00		4.30	0.157		0.69		
P1	4.00		4.40	0.157		0.173		
S	30.10		30.30	1.185		1.193		

Table 6. ISOTOP dimension values



3 Ordering information

Order code	Marking	Package	Weight	Base qty ⁽¹⁾	Delivery mode
STTH20004TV1	STTH20004TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

Table 7. Ordering information

1. This product is supplied with 40 terminal screws and washers for each tube. The screws and washers are supplied in a separate pack with the order.

4 Revision history

Date	Revision	Changes
18-Oct-2005	1	First issue.
15-Sep-2011	2	Added insulated package information in <i>Features</i> .
20-Jun-2014	3	Updated ECOPACK [®] statement, <i>Table 2</i> and <i>Table 3</i> .

Table 8. Document revision history



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